

1 Overview

DP3153S is a 16-channel low-transition PWM constant-current drive chip designed for LED displays. It integrates high-precision current generation circuit technology on-chip, so that the current error between chips can be controlled within 2.0%, and the new low-gray and high-brush mode is added to improve low-gray refresh rate. And integrated with a number of lifting LED display, the exclusive technology of display effect can bring more improvements.

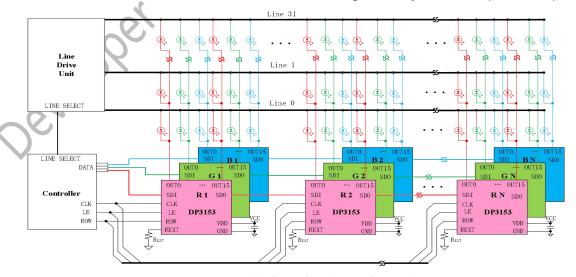
2 Features

- Power supply voltage range: 2.6 ~ 5.5V
- Operating temperature range: -40°C ~ 85°C
- Scanned area: 1 ~ 32 scans, arbitrarily adjustable
- 16 constant current output channels
- Support non-external resistor mode
- Constant current output range
 - 0.5mA ~ 18mA (V_{out} =0.3V)
 - 0.5mA ~ 25 mA $(V_{out} = 0.45V)$
- Current accuracy between channels
 - Typical value : $\pm 1.2\%$ Max : $\pm 2.5\%$ (V_{out} =0.45V)
- Current accuracy between chips
 - Typical value: ±1.5% Max: ±2.0%
- High gray independent refresh, no interframe black field
- Low gray high brush, low gray supports 1~8 times display frame rate

- The highest refresh rate supports 64 times frame rate (3840Hz)
- Optimize the display state
 - improve low gray uniformity improve the first line darkening
 - improve up and down ghosting
 - improve high-low gray coupling
 - improve cross-panel coupling
- Integrated PLL produces internal GCLK with lower EMI
- Encapsulation mode: QSOP24/QFN24
- Excellent ESD features

3 Application Fields

- High refresh rate LED video display
- Monochrome two-color or full- color LED display
- High density and small pitch LED panel display



DP3153S Typical Application Schematic



Content

1 Overview1	8.1.1 Remove Ope
2 Features1	8.1.2 High and Lov
3 Application Fields1	Coupling Display B
3 Products Description4	8.1.3 Remove Gho Effects
4 Schematic Circuit Diagram5	9 Instruction and Regis
4.1 Input/Output Equivalent Circuit5	9.1 Register Instructi
4.2 Internal Circuit Block Diagram6	9.2 Data Instructions
5 Parameter List7	9.3 Single/Double M
5.1 Maximum Limit Parameter7	9.4 Write Register
5.2 ESD Rating7	
5.2.1 Contact ESD7	9.5 Register Singal S
5.3 Electrical Characteristics (Unless otherwise specified,	9.6 ROW Signal Send
$VDD=3.5V\sim5V,\ Ta=25^{\circ}C)$	9.7 PWM Display Mo
5.4 Dynamic Characteristics (Unless otherwise specified,	9.7.1 General Fram
VDD=3.5V~5V, Ta=25°C)	9.7.2 High Gray Da Synchronization M
6 Test Circuit Diagram11	9.7.3 High-gray da
6.1 Test Circuit 111	Asynchronous Mo
6.2 Test Circuit 211	9.7.4 Low Gray Hig
6.3 Test Circuit 312	9.8 Relevant Configu
6.4 Test Circuit 412	9.8.1 Number of R
6.5 Test Circuit 513	9.8.2 Row Gray Lev
6.6 Test Circuit 613	9.8.3 PWM Display
6.7 Test Circuit 714	9.8.4 Internal Gray
7 Typical Characteristic Diagram14	9.8.5 PWM Graysc
7.1 Constant Current Source Accuracy Test Chart14	Generation
7.1.1 Inter-chip Current Error14	9.8.6 Calculated th
7.1.2 Inter- channel Current Error15	9.9 Open Circuit Det
7.2 Constant Current Source Inflexion Point15	Spots
7.3 Adjust Output Current by An External Resistor17	9.10 Register
7.4 Resistive-free Model with Current Adjusted by	10 Encapsulation Cooli
register17	11 Load Terminal Volta
8 Typical Display Effect Sample Image18	12 Encapsulation Infor
8.1 Display Effect18	13 Official Announcem

8.1.1 Remove Open Circuit Bad Spot Crosses.18
·
8.1.2 High and Low Gray Interference and Coupling Display Bad effect Optimization 18
8.1.3 Remove Ghostiness and Bandless Lighting Effects
9 Instruction and Register
9 Instruction and Register
9.2 Data Instructions20
9.3 Single/Double Mode Switch21
9.4 Write Register22
9.5 Register Singal Sending Way22
9.6 ROW Signal Sending Way23
9.7 PWM Display Mode23
9.7.1 General Frame Synchronization Mode25
9.7.2 High Gray Data Refresh Frame
Synchronization Model Independently25
9.7.3 High-gray data Independently Refreshes Asynchronous Mode25
9.7.4 Low Gray High Bruch Mode26
9.8 Relevant Configuration of PWM Display26
9.8.1 Number of Row Scans Configured26
9.8.2 Row Gray Levels Configuration26
9.8.3 PWM Display Packet Configuration26
9.8.4 Internal Grayscale Clock Configuration26
9.8.5 PWM Grayscales Series & Gamma
Generation27
9.8.6 Calculated the Display Time for Each Row27
9.9 Open Circuit Detection and Removal of Bad Spots27
9.10 Register29
10 Encapsulation Cooling Power (P _D)31
11 Load Terminal Voltage(VLED)32
12 Encapsulation Information33
13 Official Announcement35



Revision Record

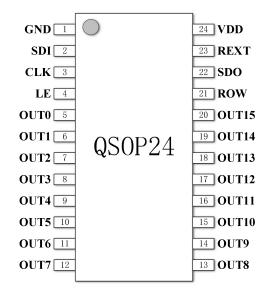
Revision Record						
Version	Date	Reviser	Revised Contents			
V1.0	2024.08	WM	Original Version			
V1.1	2025.02	WM	Modify the QFN24 Pin Definition Diagram			
Oe			Selectronics Confidential			

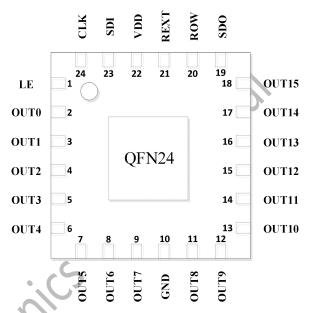
2025/2/25 DP3153S_REV1.1_EN



3 Products Description

Pin Definition





QSOP24 Pin Definition Diagram

QFN24 Pin Definition Diagram

Pin Description

QSOP24 Pin No.	QFN24 Pin NO.	Pin Name	Pin Description
1	22	GND	Chip Grounding Terminal
2	23	SDI	Serial Data Input Terminal
3	24	CLK	Serial Clock Input
4	1	LE	Data and Instruction Latch End, different LE length represents different instructions
5 ~ 20	2~9 11~18	OUT0 ~ OUT15	Constant Current Output Terminal
21	20	ROW	Row Switching Signal
22	19	SDO	Serial Data Output
23	21	REXT	Connect the External Resistance Terminal
24	10	VDD	Chip Power Terminal

QSOP24 Pin Description

Product Purchase Information

Product Name	Encapsulation mode	Packing Method	Quantity/Disc	Humidity Level
DD04506	QSOP24	Tape	4000	
DP3153S	QFN24	<u>'</u>		MSL=3

DP3153S REV1.1 EN

2025/2/25

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Product Marking



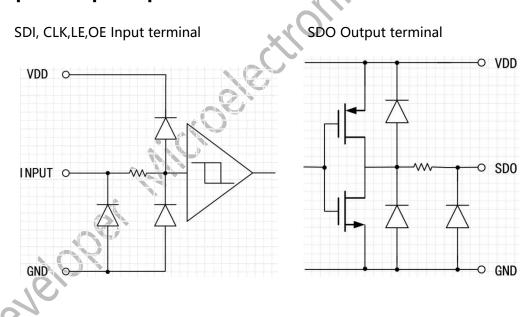
QSOP24



DP3153S is the product name XXXXXX represents th product batch number

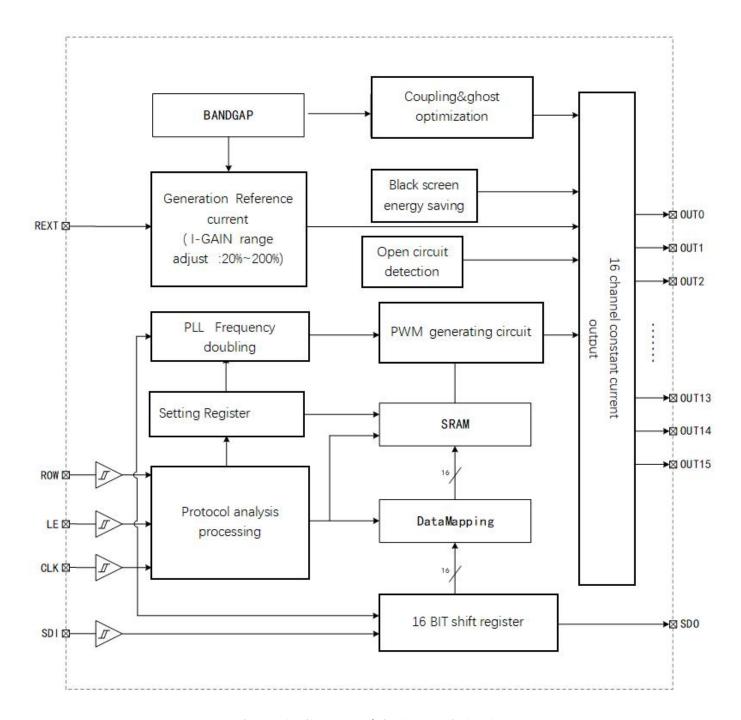
4 Schematic Circuit Diagram

4.1 Input/Output Equivalent Circuit





4.2 Internal Circuit Block Diagram



A Schematic diagram of the internal circuit

2025/2/25 DP3153S_REV1.1_EN



Parameter List

5.1 Maximum Limit Parameter

Project	Symbol	Rated Value	Unit
Supply Voltage	V _{DD}	0 ~ 5.5	V
Output Current	Io	30	mA
Input Voltage	V _{IN}	-0.4 ~ V _{DD} +0.4	V
Output withstand voltage	V _{OUT}	11	V
clock frequency	F _{CLK}	25	MHz
Operating Temperature	T _{opr}	£ (O) 3	-
Storage Temperature	T_{stg}	-55 ~ 150	°C

- All voltage values are based on the chip grounding terminal (GND) as a reference point, and the test temperature for the maximum limit parameter is 25°C.
- If the actual working conditions exceed the specified value may cause permanent damage to the components; If the actual operating conditions are slightly below the maximum and work for a long time, the reliability of the component may be reduced. The above values are only partially specified, and this product does not support functional operation under other conditions outside the specifications.
- The maximum peak welding temperature of surface paste products shall not exceed 260°C. The temperature curve shall be set by the factory according to J-STD-020 standard, the actual situation of the factory and the solder paste manufacturer's suggestion.

5.2 ESD Rating

5.2.1 Contact ESD

Symbol	С	ondition	Min Value	Typical Value	Max Value	Unit
	Human-body	OUTn Pin-GND	-	-	-	kV
	model (HBM) ¹	OTHER Pin-GND	-	-	-	kV
$V_{(ESD)}$	Machine Mode	OUTn Pin-GND	-	-	-	kV
-01	(MM) ²	OTHER Pin-GND	-	-	-	kV

- [1] The minimum HBM model ESD voltage for all pins complies with the Class-3B standard of JEDEC JS-001-2017 document.
- [2] The minimum MM model ESD voltage for all pins complies with the Class-C standard in JEDEC EIA/JESD22-A115C document.

5.3 Electrical Characteristics (Unless otherwise specified, VDD=3.5V~5V, Ta=25°C)

Project Symbol Test Test Condition	Mini	Typical	Max	Unit
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		Circuit			Value	Value	Value	
	VR_TT			R _{EXT} =1K)%,T _a =25℃	-	1.533	-	V
DEVT voltage	VR_LT		$V_{DD}=5V$	T _a =-40°C	-	1.56	-	٧
REXT voltage characteristics	VR_HT	1	R _{EXT} =1K IGAIN=100%	T _a =85°C	-	1.495	-	V
	VR_LV		T _a =25°C	V _{DD} =5.5V	-	1.535	1-	V
	VR_HV		R _{EXT} =1K V _{DD} =2.6V		-	1.521	(Q-)	V
	V _{OUT1}		V _{DD} =5.0V	IOUT=18mA	-	350	-	mV
	V_{OUT2}		R _{EXT} =1k	IOUT=9mA	-	290	-	mV
Constant current	V _{OUT3}	2	拐点等级 0	IOUT=4.5mA		260	-	mV
output inflection point	V _{OUT4}	2	V _{DD} =5.0V	IOUT=18mA	0	460	-	mV
	V _{OUT5}		$R_{EXT}=1k$	IOUT=9mA	-	390	-	mV
	V _{OUT6}		拐点等级 1	IOUT=4.5mA	-	360	-	mV
Constant current	IOUT	2	拐点等级 0		0.5	-	18	mA
source output range	IOUT1	2	拐点等级 1		0.5	-	25	mA
Inter-chip output current error	DCHIP	2	VDS=0.6V		_	±1.5	± 2.0	%
Output current error between channels	DCHL	2	VDS=0.6V		_	± 1.2	±2.5	%
Constant current error/VDS variation	%/ΔVDS	2	VDS=0.3~3.0V		_	_	± 1.0	%/V
Constant current error /VDD variation	%/ΔVDD	2	VDD=3.5V~5.0V		_	_	± 1.0	%/V
output voltage at ON	V _{O(ON)}	2	OUT0~	OUT15	0.3	-	V_{DD}	V
High SDO drive Level	ЮН	2	VDD=5V		_	-22	_	mA
current Low Level	IOL	3				23	_	mA
Output High Level	VOH	4	IOH=-1mA		4.6	_	_	V
Level Low Level	VOL	4			_	_	0.4	V
High level logistic input voltage	V _{IH}	F		-	0.7*V _{DD}	-	V _{DD}	V
Low level logistic input voltage	V _{IL}	5		-	GND	-	0.3*V _D	V

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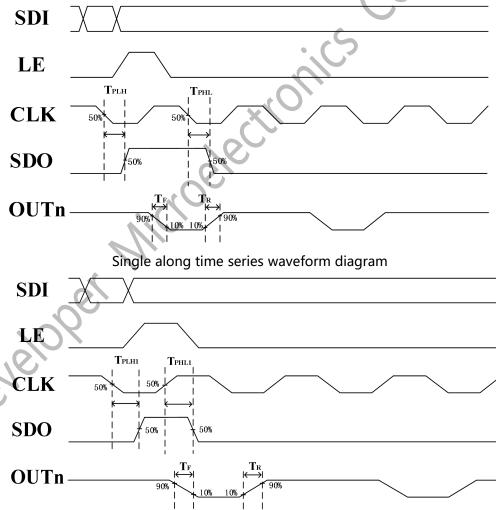


I _{DD1} I _{DD3} I _{DD4}	6	R _{EXT} =3K, White Screen IOUT=6mA, Refresh rate 3840 R _{EXT} =3K, Black Screen IOUT=6mA, Capability Priority R _{EXT} =3K, Black Screen IOUT=6mA, Low power consumption priority R _{EXT} =3K, Black Screen IOUT=6mA, lowest power consumption White Screen IOUT=6mA, Refresh Rate 3840	- - - -	4.69 2.95 1.29 0.68	-	mA mA	
I _{DD4}	6	IOUT=6mA, Capability Priority R _{EXT} =3K, Black Screen IOUT=6mA, Low power consumption priority R _{EXT} =3K, Black Screen IOUT=6mA, lowest power consumption White Screen IOUT=6mA, Refresh Rate	- - - - -	1.29	<u>-</u>	mA	
I _{DD5}	6	IOUT=6mA, Low power consumption priority R _{EXT} =3K, Black Screen IOUT=6mA, lowest power consumption White Screen IOUT=6mA, Refresh Rate	- - - - - - - - - - - - - - - - - - -	0.68	<u>-</u>		
I _{DD1}		IOUT=6mA, lowest power consumption White Screen IOUT=6mA, Refresh Rate	OU	.	-	mA	
		IOUT=6mA, Refresh Rate	OUI	4.26			
)	0	-	mA	
I _{DD3}	6	Black Screen IOUT=6mA,Capability Priority	-	2.88	-	mA	
resistance) screen energy- I _{DD4} ving power		Black Screen IOUT=6mA, Low power consumption priority	-	1.45	-	mA	
I _{DD5}		Black Screen IOUT=6mA, lowest power consumption	-	0.79	-	mA	
Consumption							
	•	M	consumption	consumption	consumption	consumption	



5.4 Dynamic Characteristics (Unless otherwise specified, VDD=3.5V~5V, Ta=25°C)

Project	Symbol	Test Circuit	Test Condition	Mini Value	Typical Value	Max Valule	Unit
CLK-SDO delay	TPHL			-	15	-	ns
CLK-SDO delay	TPLH		VDD=5V,	-	15	-	ns
CLK-SDO delay	TPHL1		FDCLK=12.5MHz	-	25	3	ns
CLK-SDO delay	TPLH1	7		-	15	-	ns
Constant Current Output Rise Time	TR		IOUT=10mA,		65	-	ns
Constant current output drop time	TF		ΔVOUT=3V	OUI	50	-	ns



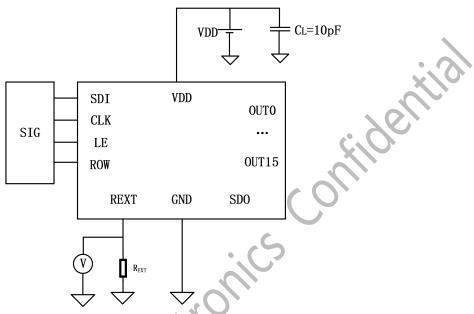
Double along time sequence waveform diagram



6 Test Circuit Diagram

6.1 Test Circuit 1

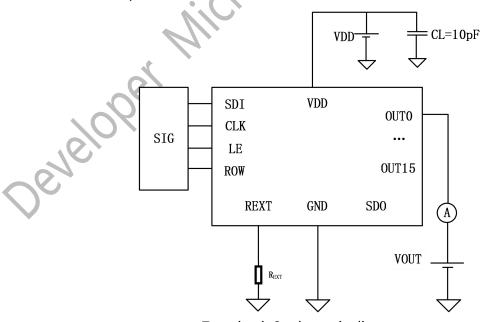
External resistance voltage



Test circuit 2 schematic diagram

6.2 Test Circuit 2

 Constant current output inflection point voltage & corresponding inflection point current (under open circuit detection)



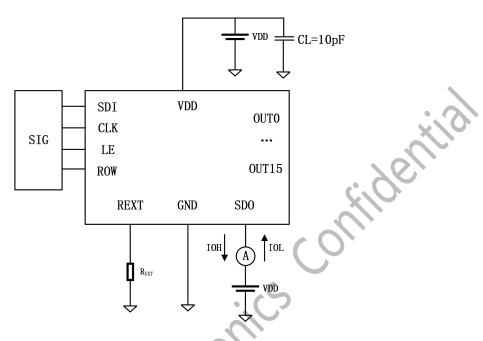
Test circuit 2 schematic diagram

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6.3 Test Circuit 3

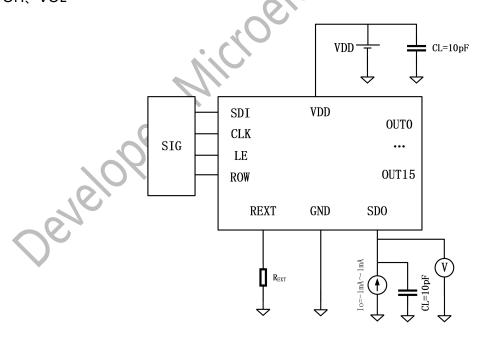
IOH, IOL



Test circuit 3 schematic diagram

6.4 Test Circuit 4

VOH, VOL



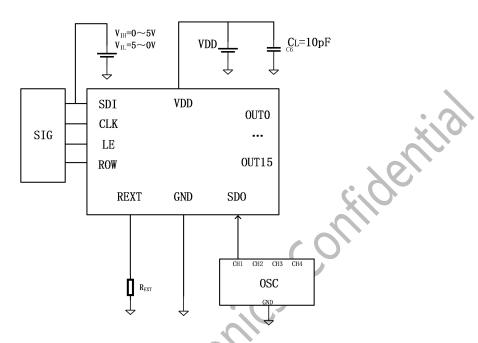
Test circuit 4 schematic diagram

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6.5 Test Circuit 5

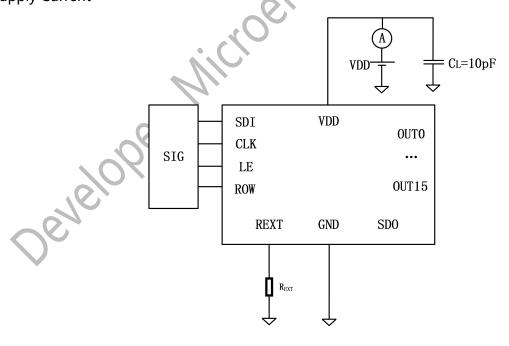
VIH, VIL



Test circuit 5 schematic diagram

6.6 Test Circuit 6

Supply Current



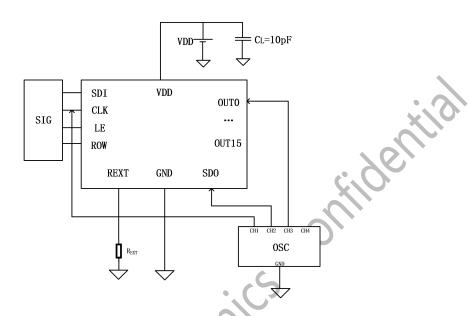
Test circuit 6 schematic diagram

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6.7 Test Circuit 7

Dynamic Characteristic



Test circuit 7 schematic diagram

7 Typical Characteristic Diagram

7.1 Constant Current Source Accuracy Test Chart

7.1.1 Inter-chip Current Error

Inter-channel current error=

Average channel current — average of all chip channels

Average of all chip channels

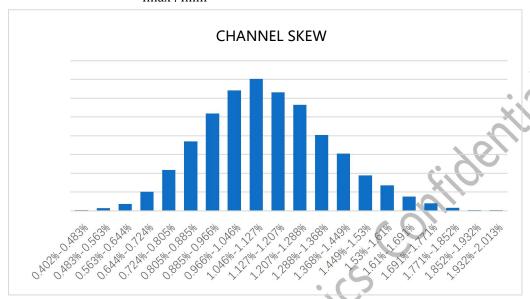


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7.1.2 Inter- channel Current Error

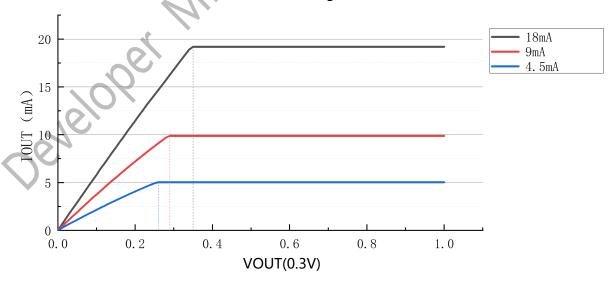
Current error between channels = $\frac{Imax - Imin}{Imax + Imin}$



7.2 Constant Current Source Inflexion Point

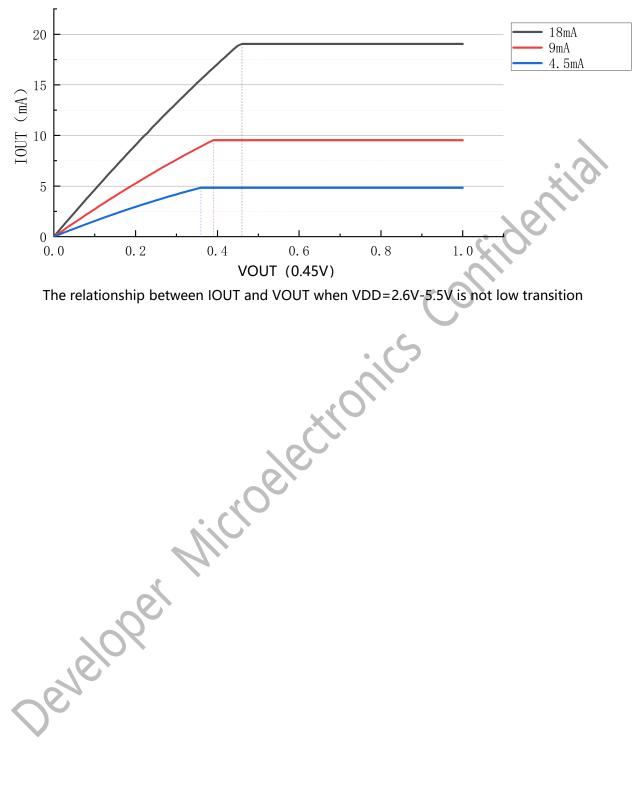
When the DP3153S is applied to the design of LED displays, the current differences between channels and even between chips are minimal. This is due to the DP3153S's excellent constant current output characteristics::

- The maximum on-chip channel current is less than ±2.5%, and the maximum on-chip current error is less than ±2.0%;
 - When the load terminal voltage (Vout) changes, the stability of the output current is not affected, as shown in the figure below:



The relationship between IOUT and VOUT when VDD=2.6V-5.5V is low transition

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The relationship between IOUT and VOUT when VDD=2.6V-5.5V is not low transition

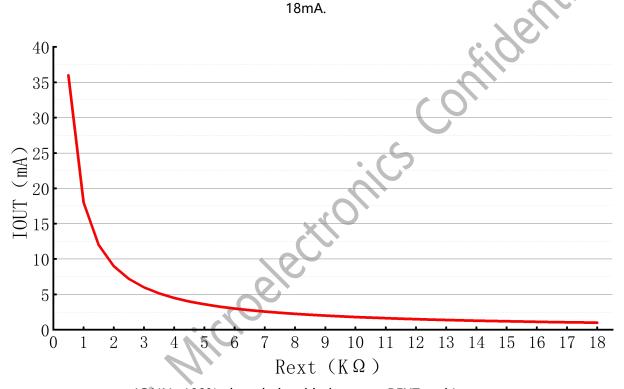


7.3 Adjust Output Current by An External Resistor

Output current value is calculated by the following formula:

$$IOUT = \frac{IGAIN*18}{Rext}$$
 , 20% \leq IGAIN \leq 200%

The REXT in the formula is the resistance to the ground of the chip's 23PIN REXT port. For example, when the current gain IGAIN=100%, REXT=1k Ω , the output current value can be obtained by calculating the formula



IGAIN=100%, the relationship between REXT and lout

7.4 Resistive-free Model with Current Adjusted by register

Output current value is calculated by the following formula:

lout = [70uA + 0.4uA*(reg0x0f < 6:0 > -16)]*reg0x08 < 7:0 > *(1 + 0.5*reg0x0b < 5 >)

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Typical Display Effect Sample Image

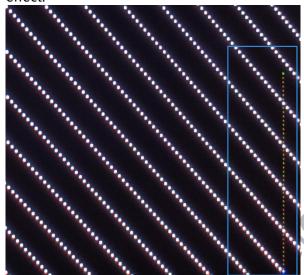
The specific display effect will be affected by the conditions of the lamp board and register parameters. The following test results are for reference only.

8.1 Display Effect

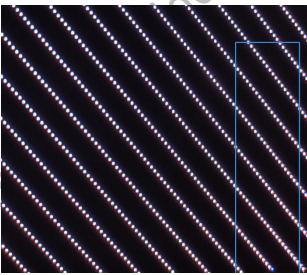
8.1.1 Remove Open Circuit Bad Spot Crosses

The following is a comparison of the display effect before and after removing the open circuit bad spot cross, you can see:

Chip can remove the bad cross well after removing the open bad cross function, optimize the display



Display Effect before Removing open circuit bad spots cross



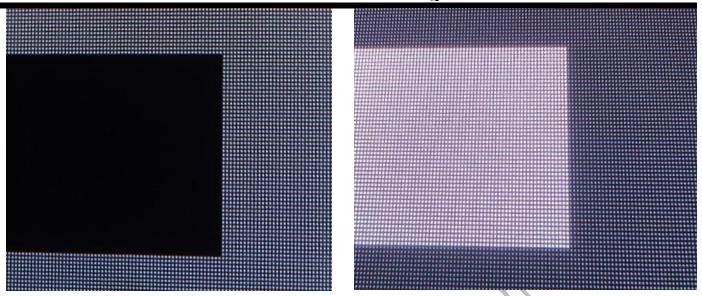
Display effect after removing the open circuit bad spot cross

8.1.2 High and Low Gray Interference and Coupling Display Bad effect **Optimization**

The following figure is the optimization effect of high-low gray interference and coupling display poor effects can be seen:

- The low gray coupling of the block and the low gray coupling of the white block are not sensed.
- Chip show good display effect.





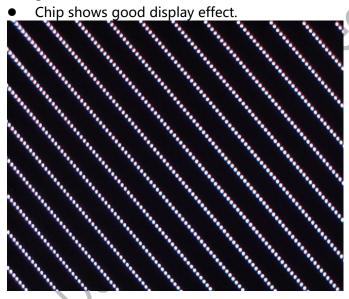
黑块低灰耦合测试显示效果

白块低灰耦合测试显示效果

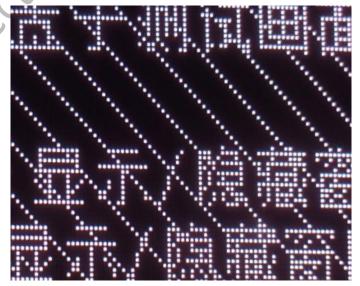
8.1.3 Remove Ghostiness and Bandless Lighting Effects

Below is the removal of ghosting and bandless lighting effect that can be seen:

- Oblique scanning ghost, text ghost and other problems cannot be observed.
- Highlight block with bright, oblique scan superimposed highlight block with bright test results are very good.

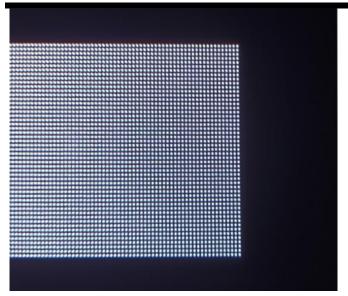


Slanted scan ghosting test display effect

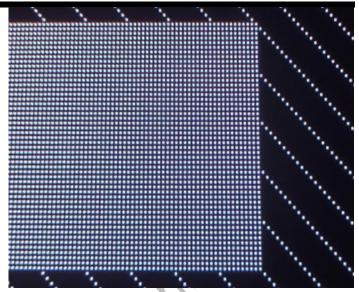


Text ghosting test display effect





Highlight block with light test display effect



Oblique scan superimposed highlight block with light test display effect

9 Instruction and Register

9.1 Register Instruction

Instruction Name	LE	Description
DATA_LATCH	1	Latch 16bit data to SRAM
DDR	2	Enter Double-edge Mode
VSYNC	3	Update Display Data
WR_CFG	5	Write Register
PRE_ACT	14	Write Enable
SDR	15	Enter Single-edge Mode

9.2 Data Instructions

Data sending Sequence	Line	Channel
1	Line 0	Channel 15 (OUT15)
2		Channel 14 (OUT14)
•••••		•••••
16		Channel 0 (OUT0)
17	Line 1	Channel 15 (OUT15)
18		Channel 14 (OUT14)

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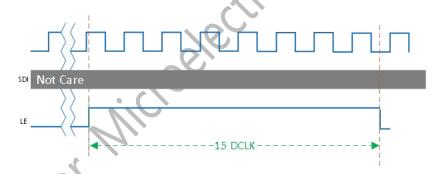


•••••			
32		Channel 0 (OUT0)	
497	Line 15	Channel 15 (OUT15)	
498		Channel 14 (OUT14)	
•••••			
512		Channel 0 (OUT0)	

9.3 Single/Double Mode Switch

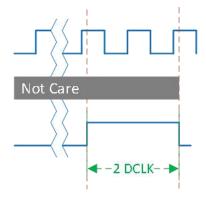
- 1. Sample SDI data with CLK rising edge in single edge mode, and sample SDI data with CLK rising edge and falling edge in double edge mode.
 - 2. CLK rising edge counting is used for fixed OE signal width
 - 3. The command for single-mode and dual-mode along mode switchover needs to be sent once after it is powered on

To enter the single-edge mode after power-on, send the command shown in the following figure:



15 DCLK edges (up + down) are set to SDR

To enter the dual-edge mode after power-on, send the command shown in the following figure



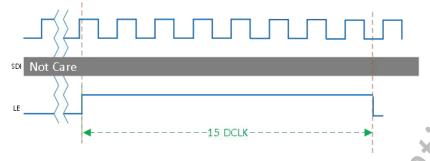
The two DCLK rising edges are set to DDR

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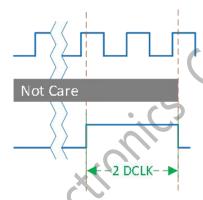
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If the customer needs to adjust the single and double edges during debugging
If already in dual edge mode and need to enter single edge mode, send the following command



In double edge mode, 15 DCLK edges (up + down) are set to SDR If already in single edge mode, you need to enter double edge mode



In single-edge mode, the two DCLK rising edges are set to DDR

9.4 Write Register

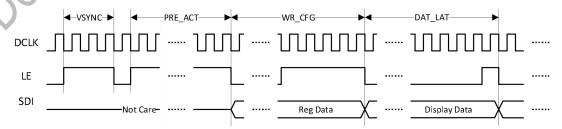
Send PRE_ACT first, then run WR_CFG, LE is 5 DCLK width, the first input 8bit is the register address bit, the last input 8bit is the data bit of the corresponding register address.

For example:

{A7, A6, A5, A4, A3, A2, A1, A0} = 8' b0000_0111; {D7, D6, D5, D4, D3, D2, D1, D0}=8' b1001_1101; That is, register 0x07 (8 b0000 0111) is set to 8' b1001 1101.

9.5 Register Singal Sending Way

The specific driving methods are as follows:



As shown in the figure above, the order of sending instructions and data in each frame:

1. Send VSYNC.

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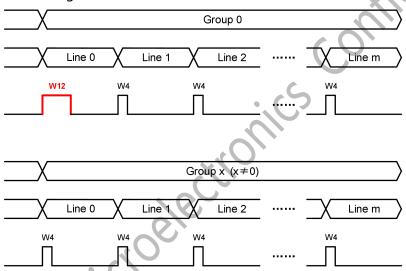
- 2. Send PRE ACT.
- 3. Send WR_CFG and write the register configuration. Each frame can only write a register value of one address, and 15 frames complete the refresh of all registers (a total of 15 valid register addresses) to save configuration time.
- 4. Send DAT LAT several times to write display data together with SDI.
- 5. The data sending bit is displayed as 16 bits.

9.6 ROW Signal Sending Way

The DP3153S integrated on-chip GCLK generation circuit changes the OE signal of the universal constant current chip to the ROW signal, using ROW the rising edge of the ROW represents the beginning of a row display, where the high level width of the row has two types, namely:

1.W12: The high-level width of the ROW is 12 DCLK width

2.W4: The high-level width of the ROW is 4 DCLK width



As shown in the figure above, when ROW signals are sent, only the first ROW of Group 1 (Line 0) needs to send ROW signals of W12, and other ROW signals are sent according to W4.

9.7 PWM Display Mode

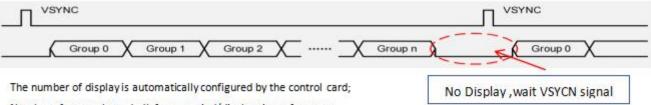
DP3153S integrated four PWM display modes:

- 1. General frame synchronization mode; 2. High-gray data independent refresh synchronous mode;
- 3. High-gray data independently refreshes asynchronous mode; 4. Low Ash High Brush mode

2025/2/25 www.depuw.com 23 DP3153S REV1.1 EN



1. Universal frame synchronization mode



Number of groups (rounded)-frame period/display time of a group;

Display time of group=(display time of a raw)*(Numbers of raw scan);

One line display time = ((2*reg0x05[7:4]+1+2*reg0x05[3:0]+1+4*reg0x[6:0]+1))/(reg0x06[2:0]+1)+break time, the answer is the Numbers of DCLK to be need;

2. High gray independent refresh synchronization mode



The number of display is automatically configured by the control card;

Number of groups (rounded)-frame period/display time of a group;

Display time of group=(display time of a raw)*(Numbers of raw scan);

One line display time = $((2^*reg0x05[7:4]+1+2^*reg0x05[3:0]+1+4^*reg0x[6:0]+1))/(reg0x06[2:0]+1)+break time, the answer is the Numbers of DCLK to be need;$

3. High gray independent refresh asynchronous mode

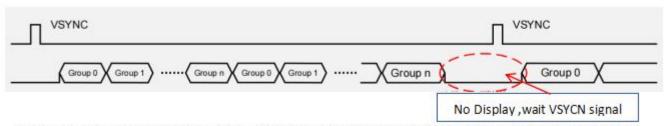


The numbers of display group is manual configured (default value 64);

Display time of group=(display time of a raw)*(Numbers of raw scan);

One line display time = ((2*reg0x05[7:4]+1+2*reg0x05[3:0]+1+4*reg0x[6:0]+1))/(reg0x06[2:0]+1)+break time, the answer is the Numbers of DCLK to be need:

4. Low Gray High brush mode



One line display time = $((2 \cdot \text{reg}0x05[7:4]+1+2 \cdot \text{reg}0x05[3:0]+1+4 \cdot \text{reg}0x[6:0]+1))/(\text{reg}0x06[2:0]+1)+\text{break time, the answer is the Numbers of DCLK to be need;}$

The numbers of display group is manual configured (default value 64);

High brush rate (int)=frame period/ (times of display all group), between every two VSYNC Signal, the Numbers of Row signal need to be send = High brush rate *Numbers of group*Numbers of Row Signal, In the diagram example, the brush rate is 2.

2025/2/25 DP3153S_REV1.1_EN www.depuw.com



9.7.1 General Frame Synchronization Mode

Working mode and related configurations as follow:

- 1. Configure REG0X0C [7:6] = 0 and set the PWM display mode to Universal Frame Sync Mode
- 2. The number of DCLK per line is calculated using the Formula
- 3. The configuration shows the number of data sets, REG0X03[6:0] = refresh rate/frame rate -1(if refresh rate is not equal to 3840 or 7680, use Depp's gamma DLL)
- 4. After VSYNC, the first Line (Line 0) of Group 1(Group 0)
- 5. Stop displaying data from the current frame until the next VSYNC comes

9.7.2 High Gray Data Refresh Frame Synchronization Model

Independently

Working mode and related configurations as follow:

- 11. Configure REG0X0C [7:6] = 2, set PWM display mode to high gray data independent refresh frame synchronization mode under this mode display refresh rate support 3840HZ ~ 7680HZ, configure display data group register reg0x03[6:0] = 127
- 2. Calculate a set of display times = frame period/(refresh rate/frame rate)
- 3. Calculate the display time of a row = a set of display times/number of rows
- 4. The DCLK number of each row is calculated according to the formula, and the formula is satisfied by adjusting the row gray level series, the DCLK frequency and the register reg0x6[1:0].
- 5. Row is sent continuously at a fixed display frequency. The frequency of the ROW is independent of VSYNC the frequency of the ROW signal = 1/1 ROW display time = 1/2 time between the rising edges of the ROW
- 6. Row 0 of group 0 sends the ROW signal of W12, other cases send the ROW signal of W4 every (group number * ROW scan number-RRB- ROW signal, only W12 W12, and in this way has been circulating.
- 7. If the refresh rate is not equal to 3840 or 7680, you need to use Depp's gamma dll.

9.7.3 High-gray data Independently Refreshes Asynchronous Mode

Working mode and related configurations as follow:

- 1. Configure REG0X0C [7:6] = 3, set the PWM display mode to high gray data independent refresh asynchronous mode
- 2. The number of DCLKS per line is calculated using the Formula

 Displays the number of data groups manually configured, the default is 64 groups (reg0x03[6:0] = 7'

 H3F).
- 3. ROW continuously transmission at a fixed display frequency without interruption, and ROW frequency is independent of VSYNC.

Row signal frequency = 1/1 ROW display time = 1/2 ROW rise edge time

- 4. Row 0 of group 0 sends the ROW signal of W12, other cases send the ROW signal of W4 per (group number (as per register configuration value) * ROW scan number-**RRB** ROW signal, only W12, and in this way has been circulating. There is no limit to the number of cycles allowed in a frame.
 - 5. Visual refresh rate = 1/(one line display time * scans)

2025/2/25 www.depuw.com 25

9.7.4 Low Gray High Bruch Mode

Working mode and related configurations as follow:

- 1. Configure REG0X0C [7:6] = 1, set PWM display mode to Low Ash High Brush Mode
- 2. Display the number of groups manually (the default is 64) . If the refresh rate is not equal to 3840 or 7680, use Depp's gamma DLL
- 3. The DCLK number of each row is calculated according to the formula, and the display time of a row is calculated
- 4. Calculate a set of display times = one line of display times * number of lines
- 5. Calculate all group display times = one group display times * number of groups
- 6. High brush rate (rounded) = frame period/display time for all groups
- 7. Before both VSYNC need to send a high brush rate * display array number * scan several ROW signals
- 8. After VSYNC, Line 1(Line 0) of Group 1(Group 0)
- 9. The data for the current frame is displayed at a high brush rate and then stopped until the next VSYNC arrival.
- 10. Visual refresh rate = frame rate * data set * high refresh rate = (3840/7680 Hz) * high refresh rate 11. The low-gray high-brush mode only needs to change the ROW signal according to the above steps, the gray level does not need to be adjusted.

9.8 Relevant Configuration of PWM Display

9.8.1 Number of Row Scans Configured

DP3153S supports up to 16 line scans, configured as REG0X02[4:0] = number of line scans -1

9.8.2 Row Gray Levels Configuration

Reg0x04[6:0] represents a row of PWM display length, one row of PWM display length = 4 * (reg0x04[6:0] + 1), maximum support 128x4 = 512 if the configuration row gray level is 128, then set reg0x04[6:0] = 7' H1F = 31

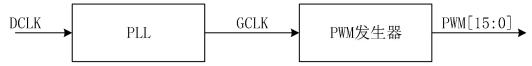
9.8.3 PWM Display Packet Configuration

Reg0x03[6:0] represents the number of PWM groups, PWM shows the number of groups = Reg0x03[6:0] + 1, the maximum number of support groups is 128 groups

In frame synchronous mode, PWM display group number = refresh rate/frame rate, configure reg0x03[6:0] = refresh rate/frame rate -1

In asynchronous mode, the PWM display packet can be configured independently (independent of the refresh rate)

9.8.4 Internal Grayscale Clock Configuration



DP3153S integrates PLL on chip to produce gray clock GCLK.

The relevant calculation formula is as follows:

2025/2/25 www.depuw.com 26



FGCLK = FDCLK*(reg0x06[1:0] + 1)

9.8.5 PWM Grayscales Series & Gamma Generation

PWM gray-scale series (maximum) = * PWM gray-scale series show grouping = 4 * (reg0x04 [lost] + 1) * (reg0x03 [lost] + 1) - 1

reg0x04[6:0]=7' h7f, reg0x03[6:0]=7' h7f

PWM gray level (maximum)=4*(127+1)*(127+1)-1=65535=16bit

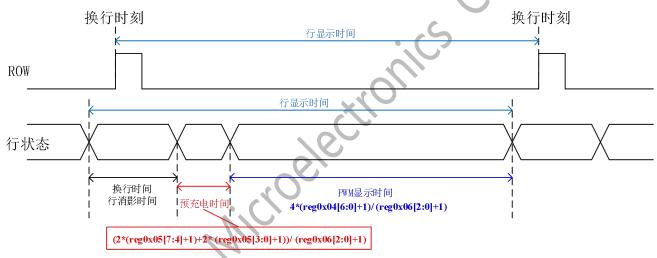
Gamma can be calculated and generated according to the PWM gray level (maximum) (this part is generated by the control card manufacturer according to their own gamma generation formula)

The maximum chip gray level only supports 16bit (low 16 bits are valid).

9.8.6 Calculated the Display Time for Each Row

The display time of each line is expressed by the number of DCLK, and the calculation formula is as follow:

(2*(reg0x05[7:4] +1) +2*(reg0x05[3:0] +1) +4*(reg0x04[6:0] +1))/(reg0x06[2:0] +1) + break timeNote: the above results are rounded.



9.9 Open Circuit Detection and Removal of Bad Spots

Selected [Remove bad spots]: reg0x0c[1]=1;

Non-selected [Remove bad spots]: reg0x0c[1]=0

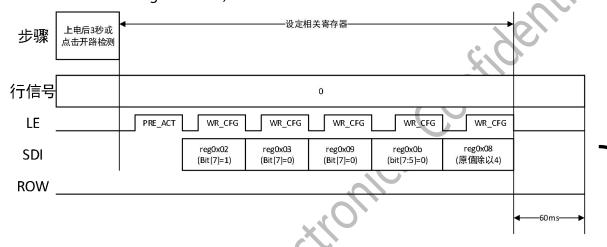
Open circuit detection timing:

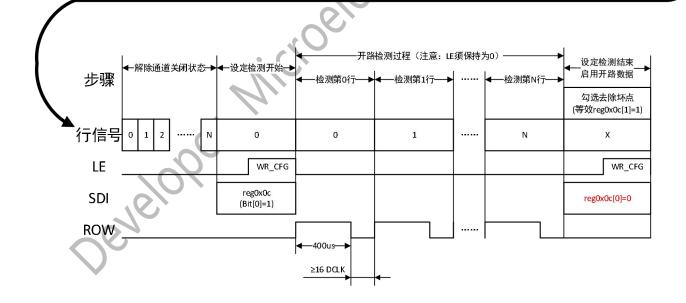
- 1. The open circuit test is performed 3 seconds after power-on or after clicking open circuit test.
- 2. Configure reg0x02[7]=1, reg0x03[7]=0 (Enable Open detection mode) Configure reg0x0b[7:5]=0 (Set constant current inflection point to the lowest) Configure reg0x08[7:0] move two digits to the right and fill the high position with 0, (configure output current to 25% of normal)
- 3. Line signal switch to line 0 and stop all line signals for one frame time (60ms)
- 4. Change the line signal, quickly scan from line 0 to the last line, and then back to line 0 (this step is mainly to avoid the closure of the output channel that exists in some line driver chips).

2025/2/25 27 www.depuw.com



- 5. Configure reg0x0c[0]=1 (Open detection mode is enabled)
- 6. Sending a Row signal, set the Row to high first and then to low. The high level time (400us recommended) is the time required for detecting a ROW, and the low level time (≥16 DCLK recommended) is the data collection and latch time.
- 7. Line feed, as many lines as need to be scanned, step 6 perform as many times. Line breaks are recommended to align with the rising edge of the ROW.
- 8. After the detection is complete, configure reg0x0c[0]=0 (Turn off open detection mode), reg0x0c[1]=1 (selected **[Remove bad spots]**).
- 9. During open-circuit detection, LE=0, DCLK is normally transmitted continuously (at least 128 DCLK between two rows are guaranteed).







9.10 Register

Register	Register Function Name	Register function description & default value	
0x02		R: 2A G: 2A B: 2A	
7	OPDET_EN_A1	OPDET_EN_A1 High effective; It must work with OPDET_EN_A2 and OPDET_EN_A3	
6		Reserved	
5:0	LINE_SET<5:0>	Scanning Lines = LINE_SET +1	
0x03		R: 3F G: 3F B: 3F	
7	OPDET_EN_A2	OPDET_EN_A2 is low valid. It must work with OPDET_EN_A1 and OPDET_EN_A3	
6:0	GROUP_SET<6:0>	Display refresh ratio =REG03<6:0>+1	
0x04	_	R: 20 G: 20 B: 20	
7		Reserved	
6:0	PWM_WIDTH<6:0>	Row GCLK number	
0x05		R: 34 G: 34 B: 34	
7:3	DISSHD_TIME_1<3:0>	Shadow elimination Time -0 to 15, total16 levels, the default value is 0	
2:0	DISSHD_TIME_2<3:0>	Shadow elimination time -0 ~15, total 16 levels	
0x06		R: 42 G: 42 B: 42	
7:3	DECOUP RAT<4:0>	Coupling optimization coefficient	
2:0	PLL_DIV<2:0>	GCLK frequency doubling0: 1 frequency doubling1: 2 frequency doubling2: 3 frequency doubling3: 4 frequency doubling	
0x07		R: 00 G: 00 B: 00	
7	Gamma_COARSE_EN	Gamma Coarse switch -1: coarse switch enabled 0: coarse switch off	
6:4	Gamma_COARSE<2:0>	Gamma 粗调等级-0~7 级,共 8 级	
3	Gamma_FINE_EN	Gamma fine-tune switch -1: fine-tune enabled 0: fine-tune disabled	
2:0	Gamma_FINE<2:0>	Gamma Fine level -0 to 7, 8 in total	
0x08		R: 7F G: 7F B: 7F	
7:0	IGAIN<7:0>	reg08[7:6] is a progression of 50% of the current gain reg08[5:0]= round (128*IGAIN/(reg08[7:6]+1))-1	
0x09		R: 60 G: 60 B: 60	
7	EN_IR	0: resistance 1: non-resistance	
6:5		Reserved	
4:0	DECOUP_1<4:0>	Coupling optimization level 1-0 ~31, total 32 levels	
0x0a		R: BE G: BE B: BE	
7:6	DECOUP_ENHANCE<1: 0>	Coupling optimization enhancement level - decreases from 0 to 3	
5		Reserved	

2025/2/25 DP3153S_REV1.1_EN



4	DISSHD EN	Extinction level switch - On :1 Off: 0	
3	DECOUP EN	Coupling optimization switch	
2:1	PIT_OPT<1:0>	Low grey pitting optimization -0 ~3, total 4 levels, the default is level 3	
0	LG ENHANCE	Low gray display effect enhancement switch	
0x0b	_	R: 28 G: 30 B: 31	
7:5	CORNER <2:0>	Constant current output inflection point level 0: low inflection point (0.18 V - 0.3 V) corresponds to the current range of 0.5mA~18mA 1: Non- low inflection point (0.3 V - 0.45 V) corresponds to the current range of 0.5mA~25mA	
4:0	DISSHD_LEVEL<4:0>	Shadow Elimination level, 0~31 level, total 32 levels	
0x0c		R: 90 G: 90 B: 90	
7:6	SYNC_MODE<1:0>	0: frame synchronization mode1: Low gray high brush model2: High gray data independently refreshed in synchronization model3: High gray data independently refreshed in asynchronous mode	
5:4	LP_MODE<1:0>	Energy-saving model 0: Dynamic energy saving 1: Dynamic Energy saving + Black screen energy saving mode 1- Performance is preferred 2: Dynamic Energy Saving + Black screen Energy Saving mode 2- Low power consumption is preferred 3: Dynamic Energy Saving + Black Screen Energy Saving Mode 3- Extremely low power consumption	
3:2		Reserved	
1	RM_OP	Remove the bad spot function switch	
0	OPDET_EN	If both OPDET_EN_A1 and OPDET_EN_A2 are met, OPDET_EN is enabled to enter the open detection mode	
0x0d		R: 08 G: 12 B: 18	
7:5	106	Reserved	
4:0	DECOUP_LEVEL<4:0>	Coupling optimization level, 0 ~31, total 32 levels	
0x0e		R: 00 G: 00 B: 00	
7:6		Reserved	
5	PRECHA_EN	Enable coupling Optimization 2	
4:0	VS_PRECHA	Coupling optimization level 2-0 ~31, total 32 levels	
0x0f		R: 00 G: 00 B: 00	
7		Reserved	
6:0	IGAINL	'Resistance-free current regulation range +/-7.5%, step length 0.5%	
0x10		R: 00 G: 00 B: 00	
7:0		Reserved	
0x11		R: 00 G: 00 B: 00	

2025/2/25 DP3153S_REV1.1_EN



7	OPEN_EN_B	Enable coupling optimization 1
6:0		Reserved
0x12		R: 00 G: 00 B: 00
7:0		Reserved
0x13		R: 00 G: 00 B: 00
7:0		Reserved
0x14		R: 00 G: 00 B: 00
7:0		Reserved
0x15		R: 00 G: 00 B: 00
7:0		Reserved
0x16		R: 00 G: 00 B: 00
7:0		Reserved
0x17		R: 00 G: 00 B: 00
7:0		Reserved

10 Encapsulation Cooling Power (PD)

The maximum heat dissipation power of the encapsulation is determined by the formula: $P_{D(\max)} = \frac{(T_j - T_a)}{R_{th(j-a)}}$

When all 16 channels are open, the actual power is:

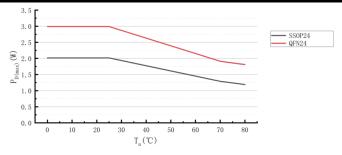
$$P_{D(act)} = I_{DD} * V_{DD} + I_{OUT} * Duty * V_{DS} * 16$$

To ensure that $P_{D(act)} \le P_{D(max)}$ output maximum current and duty cycle relationship is:

$$I_{OUT \text{ (max)}} = \frac{\frac{T_{j} - T_{a}}{R_{\text{th}(j-a)}} - (I_{DD} * V_{DD})}{V_{DS} * \text{Duty} * 16}$$

Therein T_j is the junction temperature (T_j =150°C) , T_a is the ambient temperature , V_{DS} is the constant current output port voltage , Duty is the duty cycle , and $R_{th(j-a)}$ is the thermal resistance of the encapsulation.

封装	$R_{th(j-a)}(^{\circ}C/W)$	P _{D(max)} (W)
QSOP24	62	2.01
QFN24	41.8	2.99

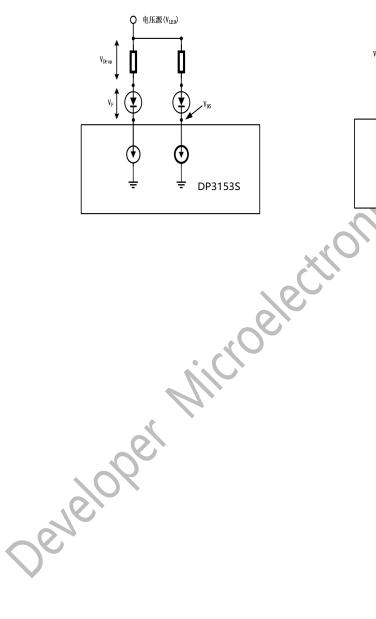


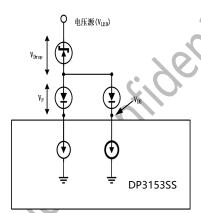
2025/2/25 DP3153S_REV1.1_EN



11 Load Terminal Voltage(VLED)

In order to optimize the heat dissipation capacity of the package, it is recommended that the best operating range of the output terminal voltage (VDS) is 0.3V to 1.0V(IOUT= 0.5-36mA). If VDS=VLED-VF and VLED=5V, the high output voltage (VDS) may cause PD (act) > PD (max); In this case, it is recommended to use the lowest possible VLED voltage for use, and an external resistor or voltage regulator can also be used as a VDROP. This results in VDS=(VLED-VF)-VDROP, which reduces the input voltage (VDS) value. The application diagram of the external series resistor or voltage regulator can be referred to the following figure.

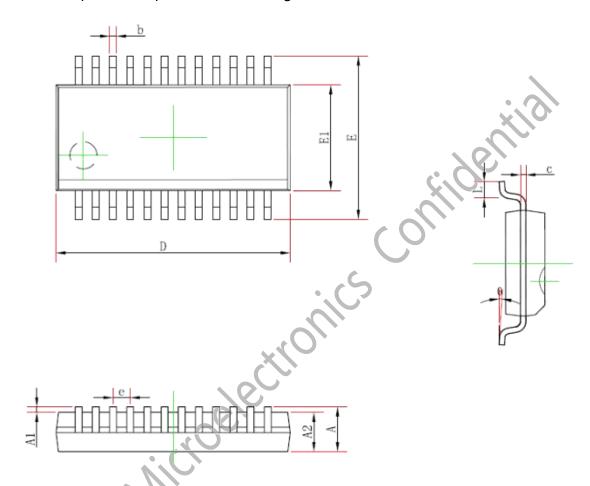






12 Encapsulation Information

QSOP24 Plastic Encapsulation Specification Drawing

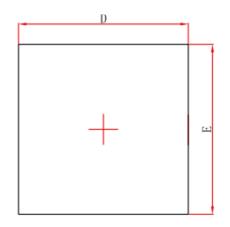


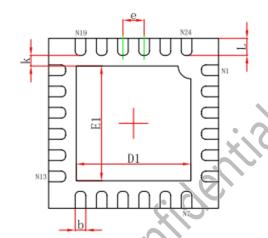
	Millimeters (mm)	
	Min	Max
Α		1.95
A1	0.05	0.35
A2	1.05	_
b	0.1	0.4
C	0.05	0.254
D	8.2	9.2
E1	3.6	4.2
E	5.6	6.5
е	0.635TYP	
L	0.3	1.5
θ	0°	10°

2025/2/25 DP3153S_REV1.1_EN



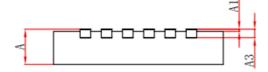
QFN24 Plastic Encapsulation Specification Drawing





Top View

Bottom Vlew



Side View

Side View		
	Millimeters (mm)	
	Min	Max
Α	0.700/0.800	0.800/0.900
A1	0.000	0.050
A3	0.203REF	
D	3.924	4.076
E	3.924	4.076
D1	2.6	2.8
E1	2.6	2.8
k	0.20MIN	
b	0.200	0.300
е	0.500TYP	
L	0.324	0.476



13 Official Announcement

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